

## Список публикаций оппонента

Оппонент – Крыжановская Наталья Владимировна, 255 работ по версии Scopus.  
Основные работы близкие к теме диссертации:

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9. Zhukov A.E., Kryzhanovskaya N.V., Maximov M.V., Egorov A.Yu., Pavlov M.M., Zubov F.I., Asryan L.V.  
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